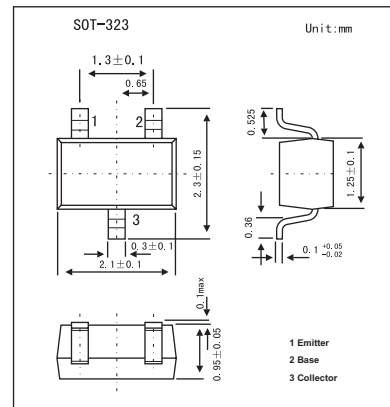


2SC4249

■ Features

- High gain: $G_{pe} = 24\text{dB}$ (typ.) ($f = 200\text{ MHz}$)
- Low noise: $NF = 2.0\text{dB}$ (typ.) ($f = 200\text{ MHz}$)
- Excellent forward AGC characteristics



■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	30	V
Collector-emitter voltage	V_{CEO}	30	V
Emitter-base voltage	V_{EBO}	3	V
Collector current	I_C	20	mA
Base current	I_B	10	mA
Collector power dissipation	P_C	100	mW
Junction temperature	T_j	125	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +125	$^\circ\text{C}$

■ Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbol	Testconditions	Min	Typ	Max	Unit
Collector cut-off current	I_{CBO}	$V_{CB} = 25\text{ V}, I_E = 0$			100	nA
Emitter cut-off current	I_{EBO}	$V_{EB} = 2\text{ V}, I_C = 0$			100	nA
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = 1\text{ mA}, I_B = 0$	30			V
DC current gain	h_{FE}	$V_{CE} = 10\text{ V}, I_C = 2\text{ mA}$	60	150	300	
Reverse transfer capacitance	C_{re}	$V_{CB} = 10\text{ V}, I_E = 0, f = 1\text{ MHz}$		0.35	0.5	pF
Transition frequency	f_T	$V_{CE} = 10\text{ V}, I_C = 2\text{ mA}$	400	650		MHz
Power gain	G_{pe}	$V_{CC} = 12\text{ V}, V_{AGC} = 1.4\text{ V}, f = 200\text{ MHz}$	20	24	28	dB
Noise figure	NF			2.0	3.2	dB
AGC voltage	V_{AGC}	$V_{CC} = 12\text{ V}, G_R = 30\text{dB}, f = 200\text{ MHz}$	3.6	4.4	5.1	V

■ Marking

Marking	HD
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